

2N4856A, 2N4857A, 2N4858A, 2N4859A, 2N4860A, 2N4861A

N-Channel Silicon Junction Field-Effect Transistor

- Choppers
- Commutators
- Analog Switches

Absolute maximum ratings at $T_A = 25^\circ\text{C}$

	2N4856A, 2N4857A, 2N4858A	2N4859A, 2N4860A, 2N4861A
Reverse Gate Source Voltage	– 40 V	– 30 V
Reverse Gate Drain Voltage	– 40 V	– 30 V
Continuous Device Dissipation	1.8 W	1.8 W
Continuous Forward Gate Current	50 mA	50 mA
Power Derating	10 mW/°C	10 mW/°C

At 25°C free air temperature:

Static Electrical Characteristics

		2N4856A 2N4859A		2N4857A 2N4860A		2N4858A 2N4861A		Process NJ132	
		Min	Max	Min	Max	Min	Max	Unit	Test Conditions
Gate Source Breakdown Voltage 2N4856A, 2N4857A, 2N4858A	$V_{(BR)GSS}$		– 40		– 40		– 40	V	$I_G = -1\mu\text{A}$, $V_{DS} = 0\text{V}$
Gate Source Breakdown Voltage 2N4859A, 2N4860A, 2N4861A	$V_{(BR)GSS}$		– 30		– 30		– 30	V	$I_G = -1\mu\text{A}$, $V_{DS} = 0\text{V}$
Gate Reverse Current 2N4856A, 2N4857A, 2N4858A	I_{GSS}		– 250		– 250		– 250	pA	$V_{GS} = -20\text{V}$, $V_{DS} = 0\text{V}$
			– 500		– 500		– 500	nA	$V_{GS} = -20\text{V}$, $V_{DS} = 0\text{V}$, $T_A = 150^\circ\text{C}$
Gate Reverse Current 2N4859A, 2N4860A, 2N4861A	I_{GSS}		– 250		– 250		– 250	pA	$V_{GS} = -15\text{V}$, $V_{DS} = 0\text{V}$
			– 500		– 500		– 500	nA	$V_{GS} = -15\text{V}$, $V_{DS} = 0\text{V}$, $T_A = 150^\circ\text{C}$
Gate Source Cutoff Voltage	$V_{GS(OFF)}$	– 4	– 10	– 2	– 6	– 0.8	– 4	V	$V_{DS} = 15\text{V}$, $I_D = 0.5\text{ nA}$
Drain Saturation Current (Pulsed)	I_{DSS}	50		20	100	8	80	mA	$V_{DS} = 15\text{V}$, $V_{GS} = 0\text{V}$
Drain Cutoff Current	$I_{D(OFF)}$		250		250		250	pA	$V_{DS} = 15\text{V}$, $V_{GS} = -10\text{V}$
			500		500		500	nA	$V_{DS} = 15\text{V}$, $V_{GS} = -10\text{V}$, $T_A = 150^\circ\text{C}$
Drain Source ON Voltage	$V_{DS(ON)}$		0.75 (20)		0.5 (10)		0.5 (5)	V (mA)	$V_{GS} = 0\text{V}$, $I_D = ()$

Dynamic Electrical Characteristics

Common Source ON Resistance	$r_{ds(on)}$		25		40		60	Ω	$V_{GS} = 0\text{V}$, $I_D = 0\text{A}$	$f = 1\text{ kHz}$
Common Source Input Capacitance	C_{iss}		10		10		10	pF	$V_{DS} = 0\text{V}$, $V_{GS} = -10\text{V}$	$f = 1\text{ MHz}$
Common Source Reverse Transfer Capacitance	C_{rss}		4		3.5		3.5	pF	$V_{DS} = 0\text{V}$, $V_{GS} = -10\text{V}$	$f = 1\text{ MHz}$

Switching Characteristics

Turn ON Delay Time	$t_{d(on)}$		5 (20) [–10]		6 (10) [– 6]		8 (5) [– 4]	ns (mA) [V]	$V_{DD} = 10\text{V}$, $V_{GS} = 0\text{V}$ $I_{D(ON)} = ()$ $V_{GS(OFF)} = []$ (2N4856A, 2N4859A) $R_L = 464\Omega$ (2N4857A, 2N4860A) $R_L = 953\Omega$ (2N4858A, 2N4861A) $R_L = 1910\Omega$
Rise Time	t_r		3 (20) [–10]		4 (10) [– 6]		8 (5) [– 4]	ns (mA) [V]	
Turn OFF Delay Time	$t_{d(off)}$		25 (20) [–10]		40 (10) [– 6]		80 (5) [– 4]	ns (mA) [V]	

TO-18 Package

See Section G for Outline Dimensions

Pin Configuration

1 Source, 2 Drain, 3 Gate & Case

Surface Mount

SMP4856A, SMP4857A, SMP4858A,
SMP4859A, SMP4860A, SMP4861A



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